

N-Ch SiC Power MOSFET

$V_{DS}=750V$

$I_D=8A$ ($T_J=25^\circ C$)

$R_{DSon}=380m\Omega$ ($V_{GS}=18V, T_J=25^\circ C$)

Features:

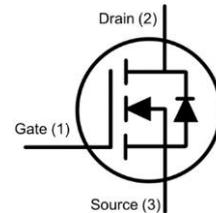
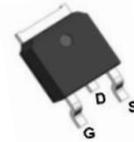
- Low On-Resistance with High Blocking Voltage
- High Speed Switching with Low Capacitance
- Avalanche Ruggedness
- Halogen Free, Rohs Compliant

Benefits:

- High Switching Frequency Operation
- High System Efficiency
- Increased Power Density
- Reduction of Heat Sink Requirements

TO-220F

TO-252



Applications:

- Switch Mode Power Supplies
- High Voltage DC/DC Converters
- Battery Chargers
- Motor Drives

Maximum Rated Valued of MOSFET

Symbol	Parameter	Test Conditions	TO-220F	TO-252	Unit
Drain-source voltage	V_{DSS}		750		V
Recommend Gate-Source Voltage	V_{GSop}		-5/18		V
Gate-Source Voltage	V_{GSmax}		-10/22		V
Continuous drain current ¹	I_D	$T_C=100^\circ C, V_{GS}=18V$	8	8	A
		$T_C=25^\circ C, V_{GS}=18V$	6	6	
Pulsed drain current	I_{DM}	t_{Pulse} limited by T_{Jmax}	15		A
Maximum power dissipation	P_{tot}	$T_C=25^\circ C, T_J=175^\circ C$	44	83	W
Operating Junction Temperature	T_J		-55~175		$^\circ C$
Storage Temperature	T_{stg}		-55~175		$^\circ C$

Notes:

1. Pulse width limited by maximum junction temperature.

Thermal Characteristic

Thermal resistance, junction-to-case	$R_{\theta JC}$	TO-220F	TO-252	Unit
		2.8	1.5	$^\circ C/W$

Electrical Characteristics of MOSFET

				Min.	Typ.	Max.	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	$T_J=25^{\circ}C$	750	-	-	V
Gate threshold voltage	$V_{GS(th)}$	$I_D=1mA, V_{DS}=V_{GS}$	$T_J=25^{\circ}C$	2.2	3.7	4.2	V
Zero gate voltage drain current	I_{DSS}	$V_{DS}=750V, V_{GS}=0V$	$T_J=25^{\circ}C$	-	-	10	μA
Gate-Source leakage current	I_{GSS}	$V_{DS}=0V, V_{GS}=-10V/22V$	$T_J=25^{\circ}C$	-	-	± 100	nA
Drain-Source On-State resistance	$R_{DS(ON)}$	$V_{GS}=18V, I_D=3A$	$T_J=25^{\circ}C$	-	380	521	m Ω
			$T_J=150^{\circ}C$	-	600	-	m Ω
Internal gate resistor	R_{Gint}	$f=1MHz, I_D=0A$	$T_J=25^{\circ}C$	-	30	-	Ω
Input capacitance	C_{iss}	$f=1MHz, V_{DS}=400V$ $V_{GS}=0V$	$T_J=25^{\circ}C$	-	205	-	pF
Output capacitance	C_{oss}			-	18	-	pF
Reverse transfer capacitance	C_{rss}			-	1.4	-	pF
Gate to source charge	Q_{GS}	$V_{DS}=400V,$ $I_{DS}=3A,$ $V_{GS}=-5V/18V$	$T_J=25^{\circ}C$	-	3.5	-	nC
Gate to drain charge	Q_{GD}			-	2.5	-	nC
Total gate charge	Q_G			-	12	-	nC
Turn-on delay time	$t_{d on}$	$V_{DS}=400V, I_D=5A$ $R_{G-ext}=47\Omega, V_{GS}=-5V/18V$	$T_J=25^{\circ}C$	-	28	-	ns
Rise time	t_r		$T_J=25^{\circ}C$	-	17	-	ns
Turn-off delay time	$t_{d off}$		$T_J=25^{\circ}C$	-	28	-	ns
Fall time	t_f		$T_J=25^{\circ}C$	-	10	-	ns
Turn-on energy loss per pulse	E_{on}		$T_J=25^{\circ}C$	-	38	-	μJ
Turn-off energy loss per pulse	E_{off}		$T_J=25^{\circ}C$	-	18	-	μJ

Characteristics of Body Diode

				Min.	Typ.	Max.	
Forward voltage	V_{SD}	$I_{SD}=5A, V_{GS}=-5V$	$T_J=25^{\circ}C$	-	4.3	-	V
Peak reverse recovery current	I_{RM}	$V_{DS}=400V, I_{SD}=5A$ $di/dt=1000A/us$	$T_J=25^{\circ}C$	-	4	-	A
Reverse recovery time	t_{rr}		$T_J=25^{\circ}C$	-	15.8	-	ns
Recovery charge	Q_{rr}		$T_J=25^{\circ}C$	-	32	-	nC

Typical Characteristics

Fig.1 Typical Forward Output Characteristics at $T_J=25^\circ\text{C}$

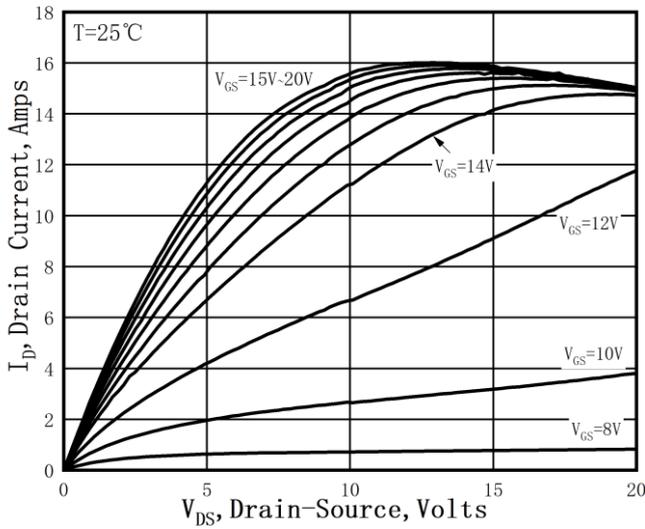


Fig.3 On-Resistance For Various Gate Voltage

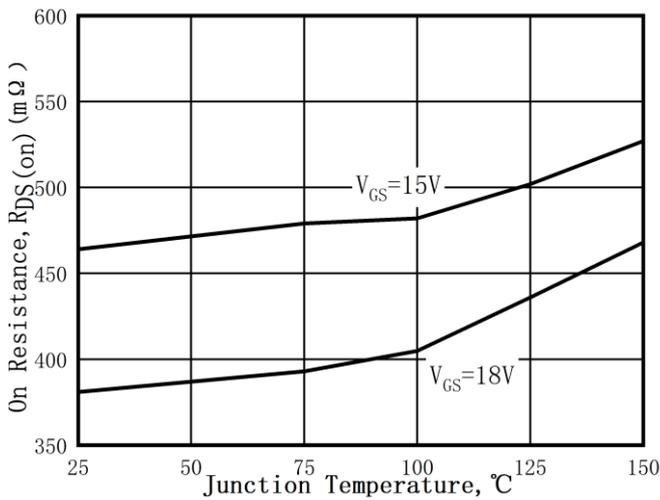


Fig.5 Body Diode Characteristics at $T_J = 25^\circ\text{C}$

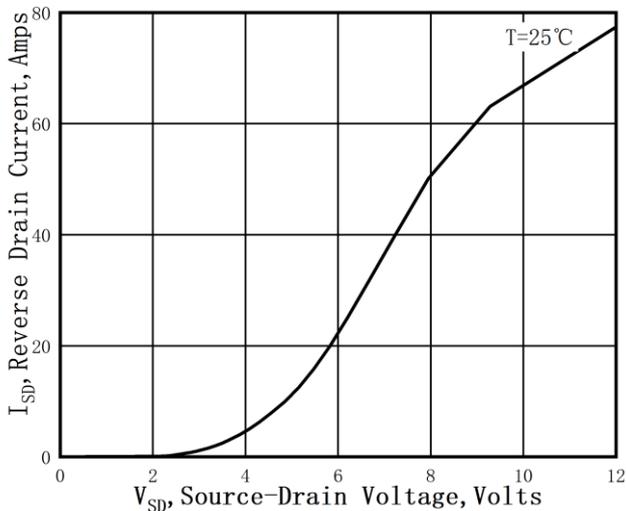


Fig.2 Typical Forward Output Characteristics at $T_J = 150^\circ\text{C}$

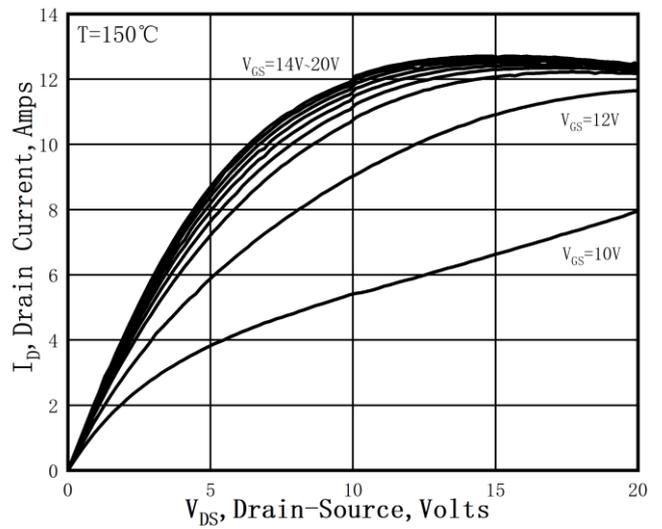


Fig.4 Threshold Voltage vs. Temperature

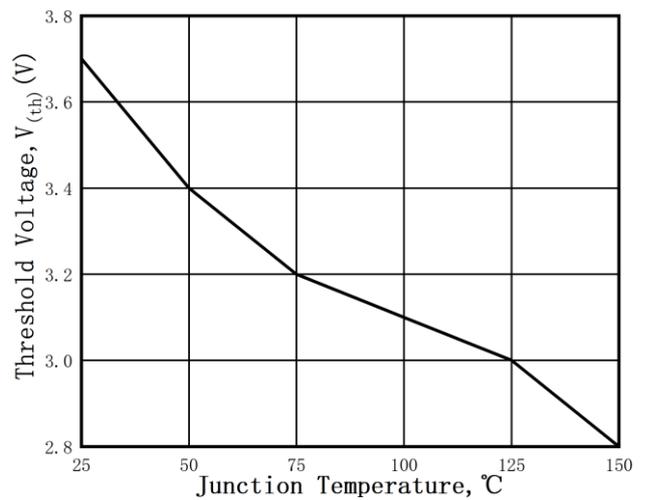


Fig.6 Body Diode Characteristics at $T_J = 150^\circ\text{C}$

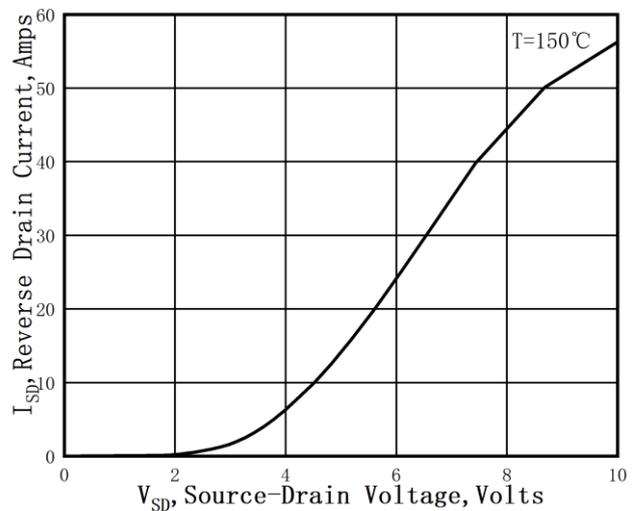


Fig.7 Transfer Characteristic for Various Junction Temperatures

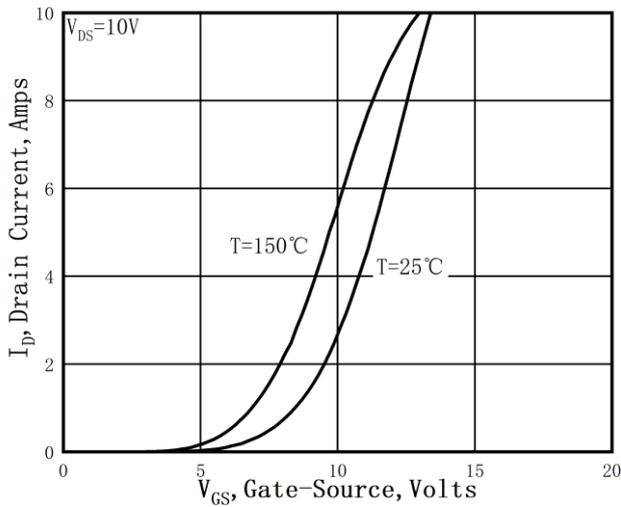


Fig.9 Gate Charge Characteristics

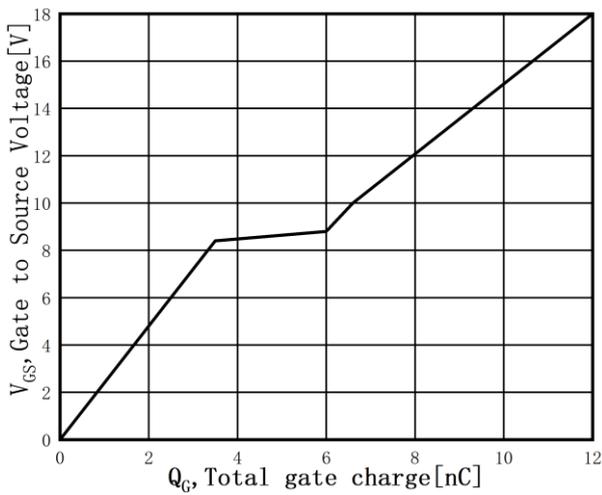


Fig.11 Maximum Power Dissipation Derating vs. Case Temperature (TO-252)

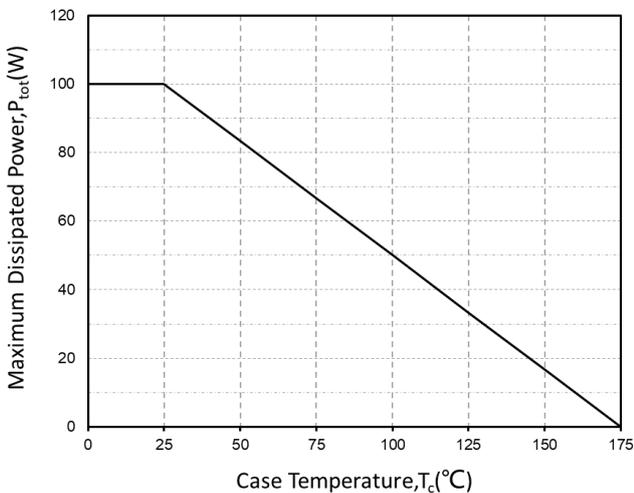


Fig.8 Capacitance vs. Drain-Source Voltage (0 – 750V)

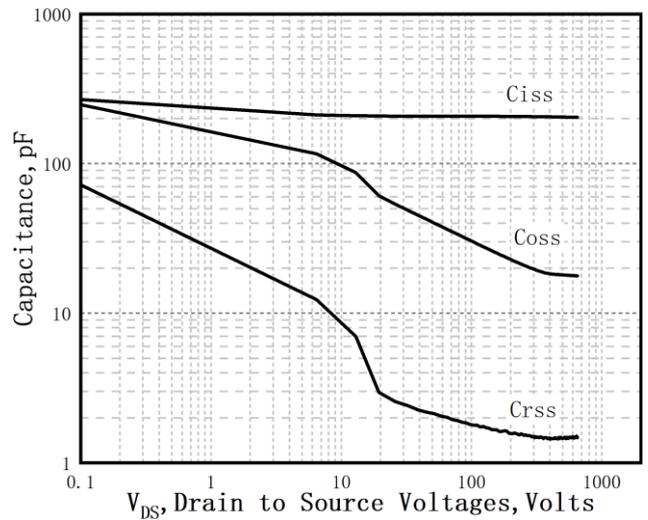


Fig.10 Maximum Power Dissipation Derating vs. Case Temperature (TO-220F)

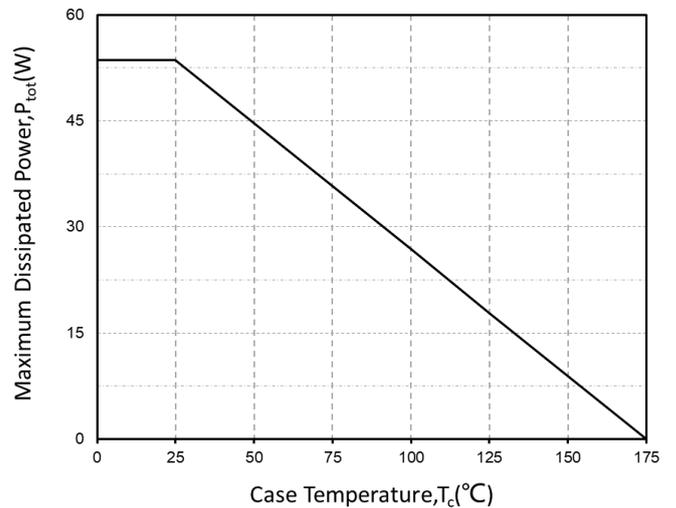


Fig.12 Transient Thermal Impedance (Junction – Case) (TO-220F)

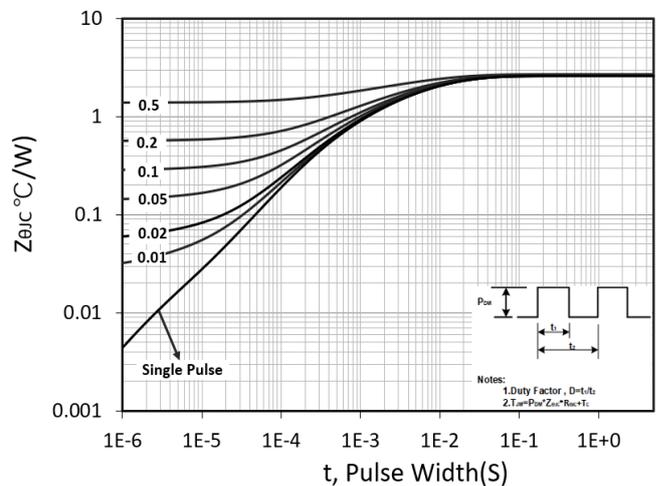


Fig.13 Safe Operating Area
(TO-220F)

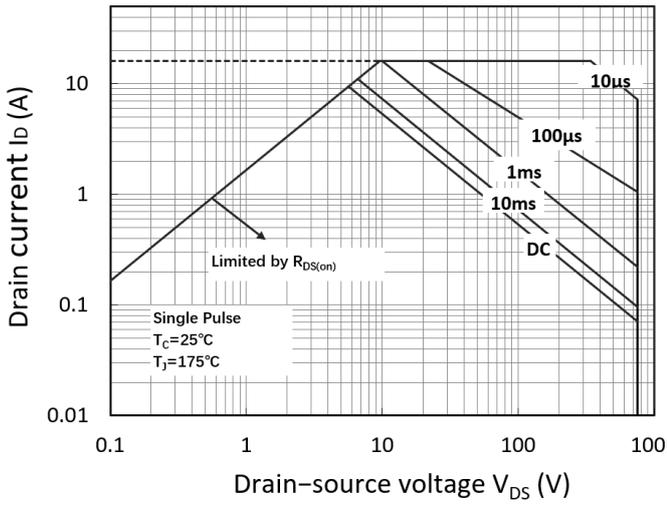


Fig.14 Transient Thermal Impedance (Junction – Case)
(TO-252)

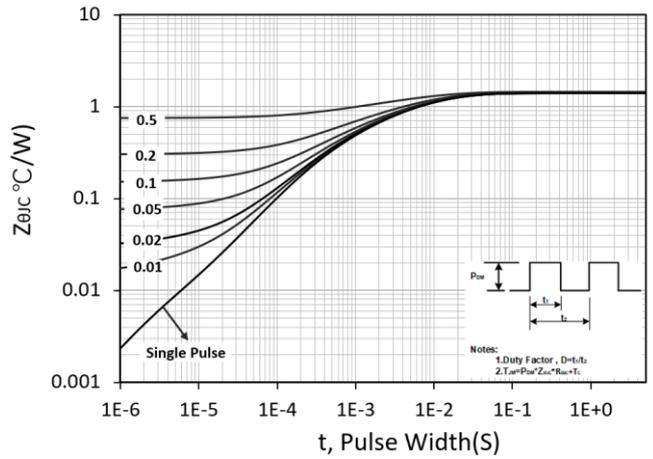
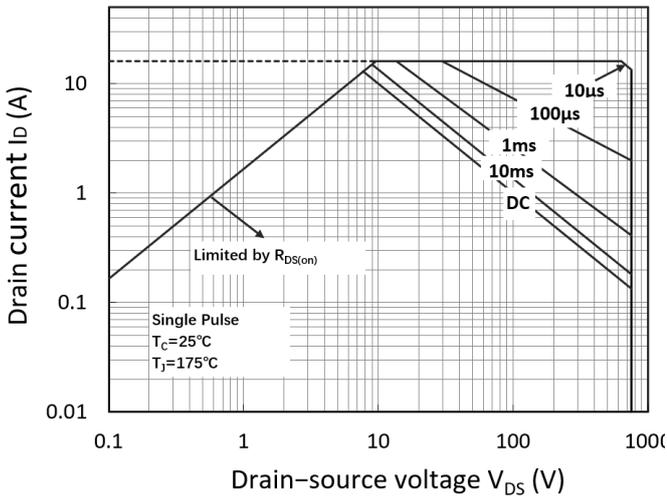
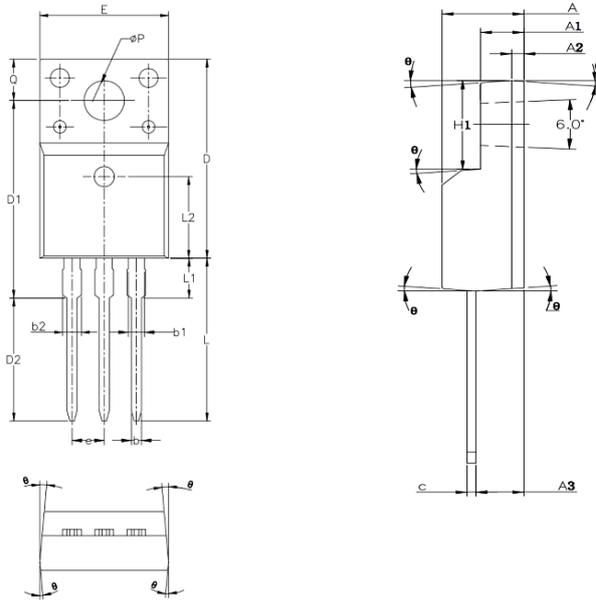


Fig.15 Safe Operating Area
(TO-252)



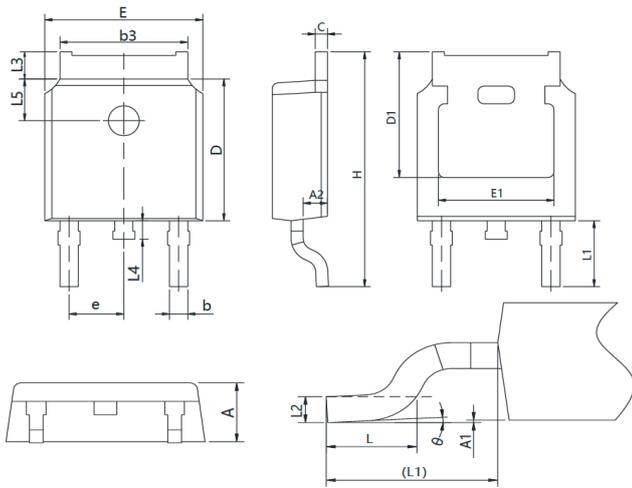
Package Dimensions

Mechanical Dimensions for TO-220F



SYMBOL	mm		
	MIN	NOM	MAX
A	4.50	4.70	4.90
A1	2.34	2.54	2.74
A2	0.70 REF		
A3	2.56	2.76	2.96
b	0.70	0.80	0.90
b1	1.18	-	1.38
b2	-	-	1.47
c	0.45	0.50	0.60
D	15.67	15.87	16.07
D1	15.55	15.75	15.95
D2	9.60	9.80	10.00
E	9.96	10.16	10.36
e	2.54 BSC		
H1	6.48	6.68	6.88
L	12.68	12.98	13.28
L1	3.25	3.40	3.55
L2	6.50 REF		
ΦP	3.08	3.18	3.28
Q	3.20	3.30	3.40

Mechanical Dimensions for TO-252



SYMBOL	mm		
	MIN	NOM	MAX
A	2.10	2.30	2.50
A1	0	--	0.15
b	0.7	0.76	0.9
b2	5.13	5.36	5.54
c	0.44	--	0.65
c2	0.45	--	0.65
D	6.00	6.10	6.20
D2	5.37	5.40	5.78
E	6.30	6.60	6.90
E1	4.83 REF		
e	2.23	2.29	2.33
H	9.7	10.10	10.5
L	1.38	1.50	1.73
L1	2.58	2.90	3.00
L2	0.50	--	0.52
L3	0.60	--	1.00
L4	0.40	0.80	1.00

Ordering Information

Part	Package	Marking	Packing method
WSCM380L75T2C	TO-220F	380L75T2C	Tube
WSCM380D75T2C	TO-252	380D75T2C	Tape and reel

Contact Information

No.1001, Shiwang(7) Road, Pudong District, Shanghai, P.R.China.201202

Tel: 86-21-50310888 Fax: 86-21-50757680 Email: market@way-on.com

WAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

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Product Specification Statement

1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

3. WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

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5. The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

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